

Transient Voltage Suppressors for ESD Protection

FEATURES:

- Low Leakage
- Response Time is Typically < 1 ns</p>
- IEC61000-4-2 Level 4 ESD Protection
- These are Pb-Free Devices
- We declare that the material of product compliance with RoHS requirements and Halogen Free.

Circuit Diagram & Pin Configuration:



SOD-882





DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
TESDN3V31BD82	ВК	10000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air discharge Contact discharge		±25	kV kV
Contact discharge		±20	KV
Total Power Dissipation on FR-5 Board (Note 1)	PD	200	mW
@ T _A =25			
Junction and Storage Temperature Range	TJ,TSTG	-55 to 150	
Lead Solder Temperature - Maximum (10	TL	260	
Second Duration)			

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0*0.75*0.62 in.

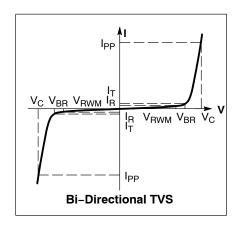




ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	C Clamping Voltage @ I _{PP}			
V _{RWM} Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}			
V _{BR}	Breakdown Voltage @ I _T			
I _T	Test Current			
P _{pk}	Peak Power Dissipation			
С	Capacitance @ V _R = 0 and f = 1.0 MHz			



ELECTRICAL CHARACTERISTICS

	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V (Not		I _T	V _C (V) @ I _{PP} = 1 A (Note 3)	V _C (V) @MAX I _{PP} (Note 3)	I _{PP} (A) (Note 3)	P _{PK} (W) (Note 3)		C (pF) :0V,f=1N	lHz
Device	Max	Max	Min	Max	mA	Max	Max	Max	Max	Min	Тур	Max
TESDN3V31BD82	3.3	0.1	5.0	6.5	1.0	7	10	6	60	8	12	16

Other voltage available upon request.

- 2. V_{BR} is measured with a pulse test current IT at an ambient temperature of 25
- 3. Surge current waveform per Figure 1.

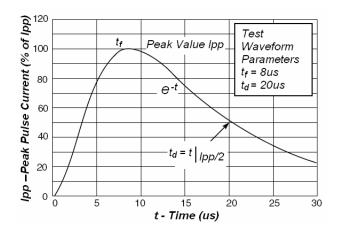


Fig1. Pulse Waveform

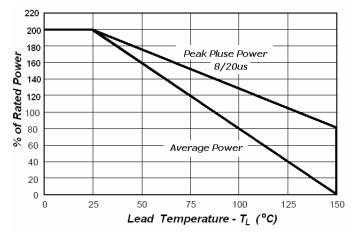


Fig2.Power Derating Curve



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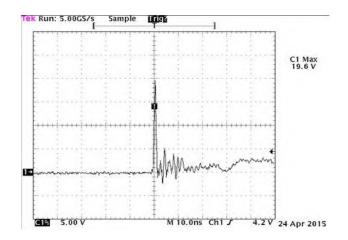


Fig3.Positive 8 kV Contact per IEC61000.4.2

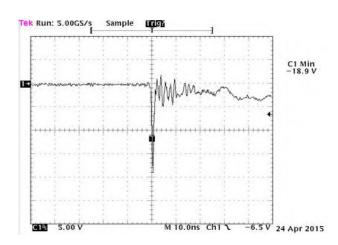


Fig4.Negative 8 kV Contact per IEC61000.4.2

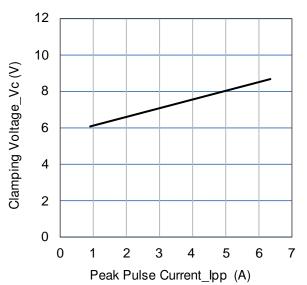


Fig5.Clamping Voltage vs. Peak Pulse Current

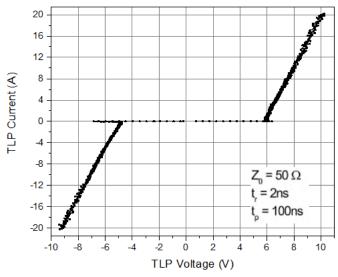
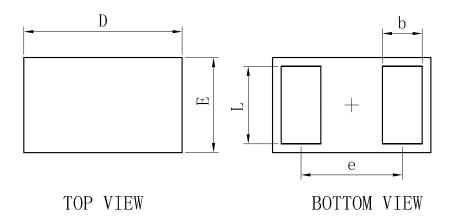


Fig6.TLP Measurement

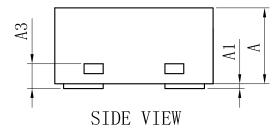


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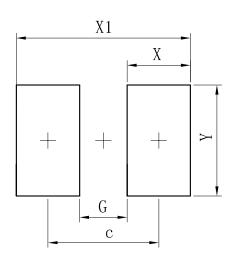
OUTLINE AND DIMENSIONS



S0D882				
Dim	Min	Тур	Max	
D	0. 95	1.00	1.05	
Е	0. 55	0.60	0.65	
е	-	0.64	ı	
L	0.44	0.49	0.54	
b	0. 20	0. 25	0.30	
A	0.43	0.48	0. 53	
A1	0 - 0.05			
A3 0. 127REF.				
All Dimensions in mm				



SOLDERING FOOTPRINT



Dimensions	(mm)
С	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70



TESDN3V31BD82

NOTICE

The information presented in this document is for reference only. Tinysemi reserves the right to make changes without notice for the specification of the products displayed herein.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tintsemi elec Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damagers resulting from such improper use of sale.

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